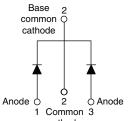


VS-MBR4045CTPbF, VS-MBR4045CT-N3

Vishay Semiconductors

Schottky Rectifier, 2 x 20 A



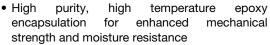


TO-220AB	Anode 0 2 Anode 1 Common 3 cathode
DUCT SUMMARY	
Package	TO-220AB

PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 20 A				
V_{R}	45 V				
V _F at I _F	0.58 V				
I _{RM} max.	95 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	20 mJ				

FEATURES

- 150 °C T_J operation
- · Low forward voltage drop
- High frequency operation





- · Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS VALUES						
I _{F(AV)}	Rectangular waveform (per device)	40	Α				
V _{RRM}		45	V				
I _{FRM}	T _C = 118 °C (per leg)	40	^				
I _{FSM}	t _p = 5 μs sine	900	— A				
V _F	20 A _{pk} , T _J = 125 °C	20 A _{pk} , T _J = 125 °C 0.58					
T _J	Range	- 65 to 150	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-MBR4045CTPbF	VS-MBR4045CT-N3	UNITS		
Maximum DC reverse voltage	V _R	45	45	V		
Maximum working peak reverse voltage	V _{RWM}	45	45	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS		UNITS	
Maximum average per		T 410.00 m-1-1 V				
forward current per dev	ice I _{F(AV)}	$T_C = 118$ °C, rated V_R		40		
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 118 °C		40	Α	
Maximum peak one cycle non-repetitive	l=o	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	900		
surge current per leg	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	210		
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.40 mH		20	mJ	
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \text{ x } V_R$ typical		3	Α	



VS-MBR4045CTPbF, VS-MBR4045CT-N3

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			
		20 A	T 05.00	0.60	V	
Maximum famuard valtage dran	V _{FM} ⁽¹⁾	40 A	T _J = 25 °C	0.78		
Maximum forward voltage drop	V _{FM} ('')	20 A	T 405 00	0.58		
		40 A	T _J = 125 °C	0.75		
	I _{RM} ⁽¹⁾	T _J = 25 °C		1		
Maximum instantaneus reverse current		T _J = 100 °C	Rated DC voltage	50	mA	
		T _J = 125 °C		95		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} , (test signal range 100 kHz to 1 MHz) 25 °C		900	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nΗ	
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	T_{J}		- 65 to 150	°C		
Maximum storage temperature range	T _{Stg}		- 65 to 175	C		
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5			
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (For D ² PAK and TO-262)	50			
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf ⋅ cm		
Mounting torque maximum		Non-lubricated tilleads	12 (10)	(lbf \cdot in)		
Marking device		Case style TO-220AB	MBR4	045CT		

Vishay Semiconductors

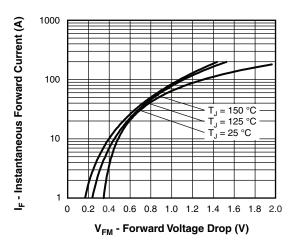


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

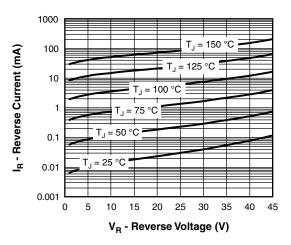


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

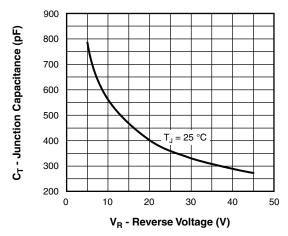


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

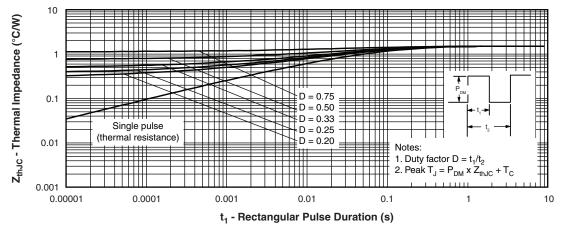


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

Vishay Semiconductors

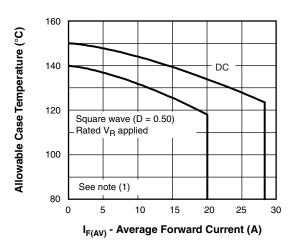


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

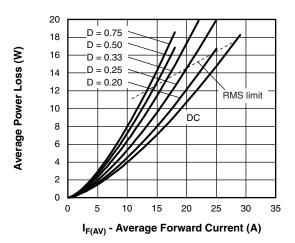


Fig. 6 - Forward Power Loss Characteristics

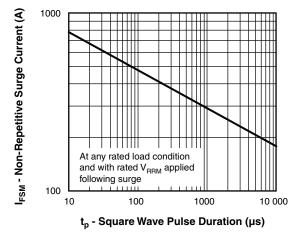


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

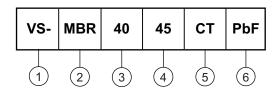
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

VS-MBR4045CTPbF, VS-MBR4045CT-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Schottky MBR series

- Current rating (40 = 40 A)

Voltage rating (45 = 45 V)

- CT = Essential part number

6 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-MBR4045CTPbF	50	1000	Antistatic plastic tube			
VS-MBR4045CT-N3	50	1000	Antistatic plastic tube			

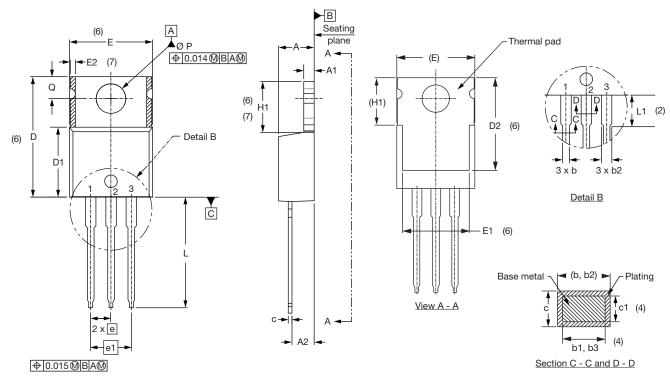
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225			
	TO-220AB -N3	www.vishay.com/doc?95028			
SPICE model		www.vishay.com/doc?95296			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead tip

Lead assignments

<u>Diodes</u>

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.